

Supplementary Materials for

Shedding light on moiré excitons: A first-principles perspective

Hongli Guo, Xu Zhang, Gang Lu*

*Corresponding author. Email: gang.lu@csun.edu

Published 16 October 2020, *Sci. Adv.* **6**, eabc5638 (2020)

DOI: [10.1126/sciadv.abc5638](https://doi.org/10.1126/sciadv.abc5638)

This PDF file includes:

Table S1

Figs. S1 to S5

Table S1. **Twist angle dependent band width and exciton binding energy.** The variation of interlayer distance (δh), VBM bandwidth, and exciton binding energy as a function of twist angle.

Angle ($^{\circ}$)	3.5	6	9.56	21.7	32.2	0	56.5
δh (\AA)	0.54	0.44	0.22	0.02	0.02	0.00	0.58
VBM bandwidth (meV)	7	25	111	617	345	1500	3
Exciton binding energy (eV)	0.43	0.42	N/A	0.43	0.39	0.50	0.42

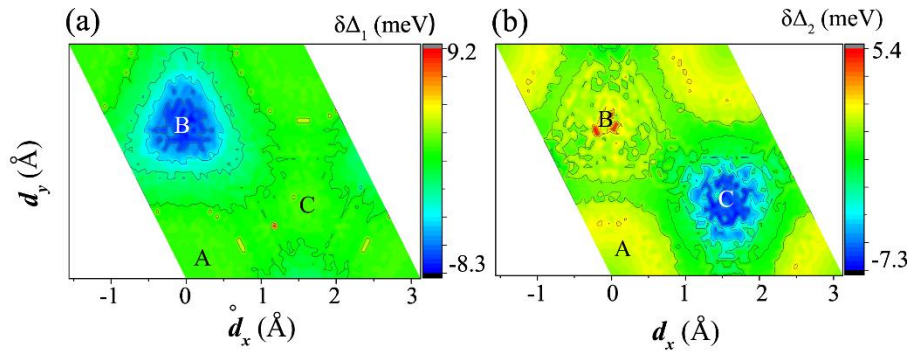


Figure S1. **Moiré modulated local intralayer gaps.** Variation of intralayer band gaps Δ_1 (a) and Δ_2 (b) as a function of d .

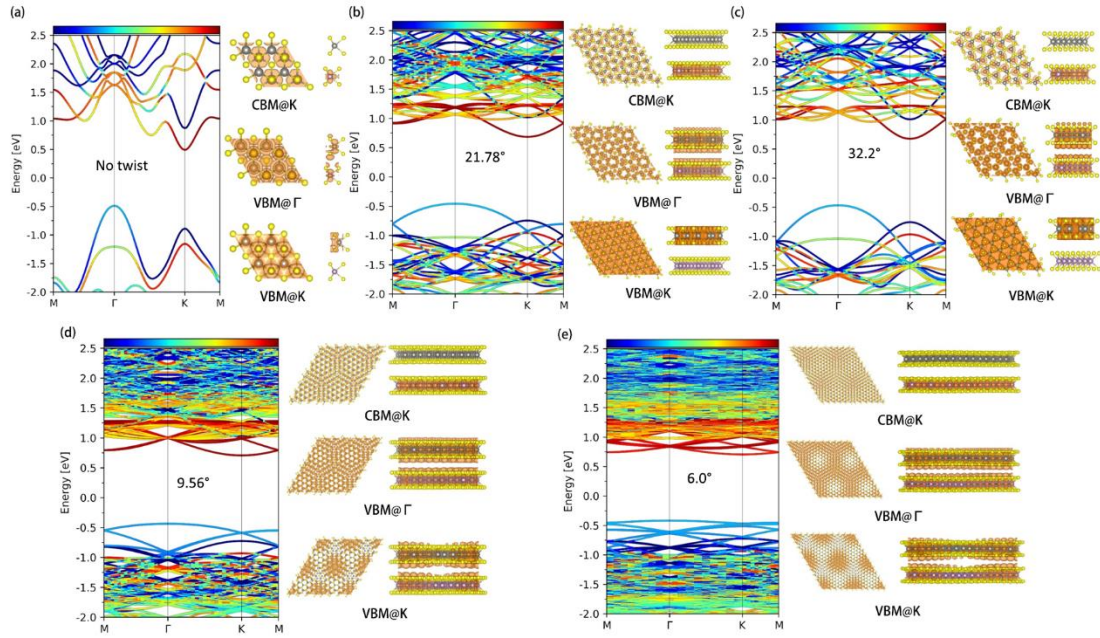


Figure S2. **Twist angle dependent electronic structures.** Band structures and charge densities of VBM and CBM for MoS₂/WS₂ heterostructures with different twist angles.

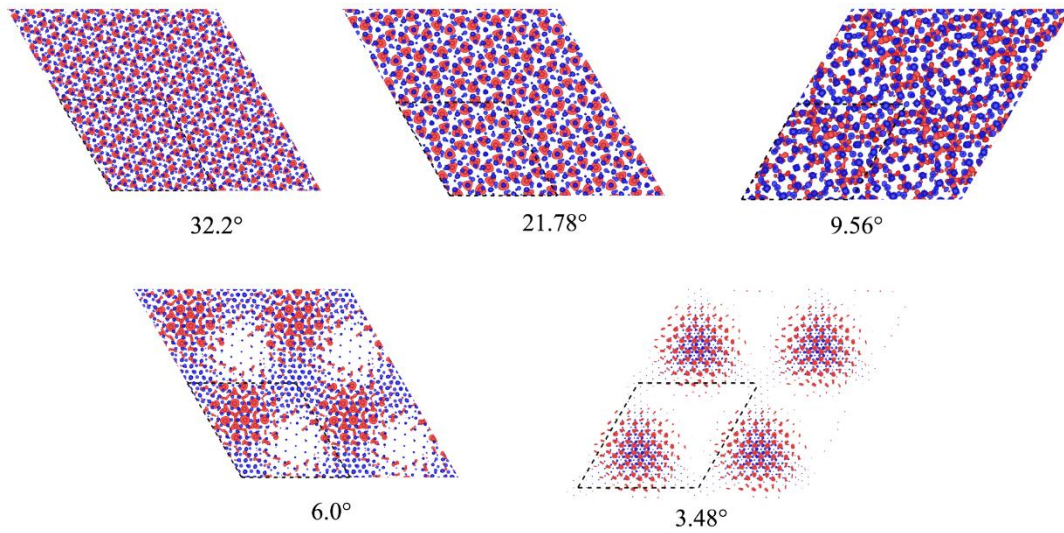


Figure S3. **Exciton charge densities of MoS₂/WS₂ heterostructures with different twist angles.**

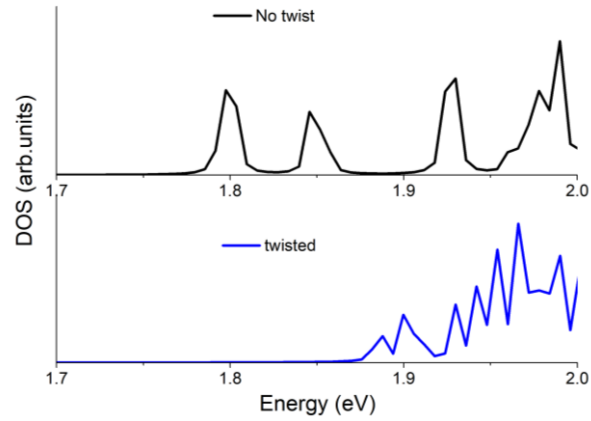


Figure S4. **Exciton energy splitting by moiré potential.** Excitonic density of states (DOS) for MoS₂/WS₂ heterostructures with $\theta=0^\circ$ (no twist) and $\theta=3.48^\circ$. The DOS of twisted heterostructure shows denser energy spacing.

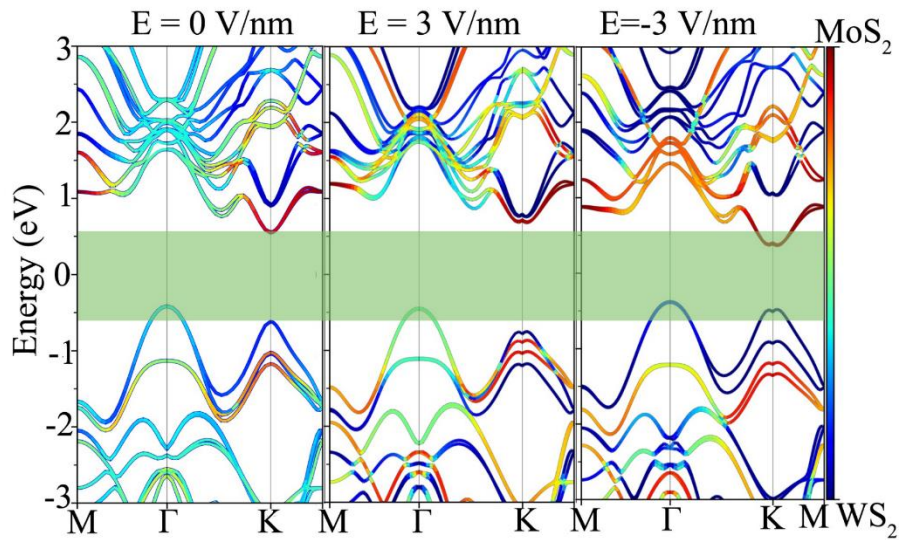


Figure S5. **Band structure of MoS₂/WS₂ heterostructure ($\theta=0^\circ$) under electric field.** PBE+SOC band structures of MoS₂/WS₂ heterostructure ($\theta=0^\circ$) under different electric fields, showing the energy level shifts that are consistent with Figure 6(a).